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Docket No.: 60188-127

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Customer Number: 20277

Nobuyo SUGIYAMA, et al

Confirmation Number: 7445

Serial No.: 10/003,434

Group Art Unit: 2826 Allowed: March 15, 2004

Filed: December 06, 2001

Examiner: Kevin V. Quinto

For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE WHICH CAN OPERATE AT HIGH SPEED WITH LOW VOLTAGE, AND MANUFACTURING METHOD THEREOF (As Amended)

REQUEST FOR ACKNOWLEDGEMENT OF THE CITED ART

Mail Stop ISSUE FEE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

We are in receipt of the Notice of Allowance dated March 15, 2004.

In reviewing the file, it is noted that we have not received acknowledgement of the Information Disclosure Statement and cited art filed February 23, 2004. Enclosed are copies of the Information Disclosure Statement, PTO-1449 and stamped return postcard acknowledgement.

Applicant hereby respectfully requests that:

the appropriately acknowledged PTO-1449 be furnished to Applicant; and the record be clarified to confirm that the cited art has been considered and made of record.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

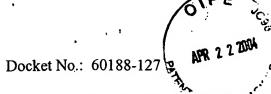
Michael E. Fogarty Registration No. 36,139

600 13th Street, N.W. Washington, DC 20005-3096 (202) 756-8000 MEF:cg Facsimile: (202) 756-8087

Date: April 22, 2004



Appli	cant:	Nobuyo SUGIYAMA, et al. Do							Docket N	o. <u>b</u>	0188-1	21			·			
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 20277

Nobuyo SUGIYAMA, et al. : Confirmation Number: 7445

Serial No.: 10/003,434 : Group Art Unit: 2826

Filed: December 06, 2001 : Examiner: Kevin V. Quinto

For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE AND

MANUFACTURING METHOD THEREOF

INFORMATION DISCLOSURE STATEMENT

Mail Stop IDS Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed more than three months after the U.S. filing date AND after the mailing date of the first Office Action on the merits, but before the mailing date of a Final Rejection or Notice of Allowance.

10/003,434

CERTIFICATION PARAGRAPH

The undersigned certifies that, to the best of his knowledge, each item of information

contained in this Information Disclosure Statement was first cited in a communication from a

foreign patent office in a counterpart foreign application not more than three months prior to the

filing of this Information Disclosure Statement as described in 37 CFR 1.97(e)(1).

Each non-English language reference was cited in a corresponding foreign application

search report or office action and its relevance discussed therein. A copy of the foreign search

report or office action, together with an English language version thereof, is attached for the

Examiner's information.

Please charge any shortage in fees due in connection with the filing of this paper, including

extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit

account.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

Michael E. Fogarty

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600 13th Street, N.W.

Washington, DC 20005-3096

(202) 756-8000 MEF:tlb

Facsimile: (202) 756-8087

Date: February 23, 2004

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				U.S. PATEN	IT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Numi	Document Number ber-Kind Code2 (# known)	Publication Date MM-DD-YYYY		Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear						
	US 5,591,652		01/07/1997	Matsushita								
		US 6,121,655		09/19/2000	Odanaka et al.							
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		$oxed{oxed}$	EP 0 530 644 A2	03/10/1993	TEXAS INSTRUMENTS INCORPORATED			In English				
		EP 0 935 293 A2		08/11/1999	MATSUSHITA ELECTRIC INDUSTRIAL CO., LTD.			In English				
,			EP 0 905 790 A2	03/31/1999	MATSUSHITA ELECTRONICS CORPORATION			In English				
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.